



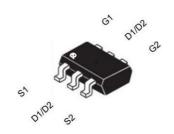


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Product Summary

- VDS = 20V,ID =6A RDS(ON), 19.5m Ω (Typ) @ VGS =4.5V RDS(ON), 25m Ω (Typ) @ VGS =2.5V
- Trench Power Technology
- Low RDS(ON)
- Low Gate Charge
- Optimized for Fast-switching Applications

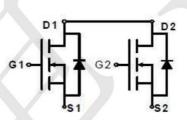
Package and Pin Configuration



Application

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial

Circuit diagram



Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Parameter		Symbol	Value	Unit
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V _{GS}	±10	V
Drain Current-Continuous ^{Note3}	TC=25℃		6	Α
Drain Current-Continuous	TC=70℃	l _D	4.8	Α
Drain Current-Pulsed ^{Note1}		I _{DM}	24	Α
Avalanche Energy ^{Note4}		Eas	7.4	mJ
Maximum Power Dissipation	TC=25℃	P _D	1.5	W
Storage Temperature Range		T _{STG}	-55 to +150	$^{\circ}$
Operating Junction Temperature Rar	nge	TJ	-55 to +150	$^{\circ}$

Thermal Resistance

Parameter	Symbol	Min.	Тур.	Max	Unit
Thermal Resistance, Junction-to-Case	Rejc)-	14.4	-	°C/W
Thermal Resistance, Junction-to-Ambient	ReJA	-	83	-	°C/W



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Electrical Characteristics (T_A = 25°C unless otherwise noted)

OFF CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _{DS} =250uA	20	-	-/	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V,V _{GS} =0V	-	=	1	uA
Gate-Body Leakage	I _{GSS}	V _{GS} =±10V,V _{DS} =0V	-	- 7	±100	nA

ON CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Gate Threshold Voltage	VGS(TH)	V _{DS} =V _{GS} ,I _{DS} =250uA	0.5	0.7	1.2	V
Dunin Course On State Desigtance	DDC(ON)	V _{GS} =4.5V,I _{DS} =3A		19.5	25	0
Drain-Source On-State Resistance	RDS(ON)	V _{GS} =2.5V,I _{DS} =3A	-	25	31.5	m Ω

DYNAMIC CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	Ciss	VD0 40V4V00 0V4	/-\	466	//	
Output Capacitance	Coss	VDS =10V, VGS = 0V,	- >	65	-	pF
Reverse Transfer Capacitance	Crss	f=1MHz	-	58	-	

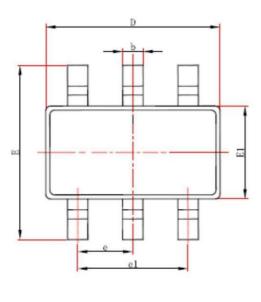
SWITCHING CHARACTERISTICS			_			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Turn-On Delay Time	T _{d(on)}	V 45VV 40V	-	15	-	
Rise Time	tr	V _{GS} =4.5V,V _{Ds} =10V,	-	17	-	
Turn-Off Delay Time	T _{d(off)}	R _{GEN} =2.5Ω	-	42	-	ns
Fall Time	t _f	ID=6A		10		
Total Gate Charge at 10V	Qg	1011 01		5.7	:	
Gate to Source Gate Charge	Q _{gs}	V _{DS} =10V,I _{DS} =6A,	-	0.8	-	nC
Gate to Drain"Miller"Charge	Q _{gd}	V _{GS} =10V	-	1.4		

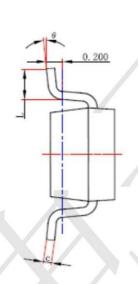
DRAIN-SOURCE DIODE CHARACTERIS	STICS AND MAXI	MUM RATINGS			·	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _{DS} =6A		-	1.2	٧

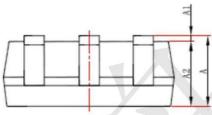


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SOT23-6 Package Outline Dimensions







CLI	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950	(BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°